Superconductivity & Non-Fermi Liquids

in domain wall networks of 2D CDW systems

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Collaborators

Funding











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Park, GYC, Lee, Yeom, Nature Communications (2019)
 Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC, Physical Review Letters (2020)
 Lee, Oshikawa, GYC, Physical Review Letters (2021)

[4] Kang, Lee, GYC, Physical Review Letters (2021)
[5] Park, Kim, GYC, Lee, Physical Review Letters (2019)
[6] Park, Lee, (...), GYC, Lee, Nature (2022) - if time allows...

Warning: I am not really a specialist of a particular material...



Based on my (*possibly wrong*) understandings on materials/experiments.

(although I consulted with many experimentalists)

Goal: Exploring Electronic Properties of Quasi-1d Systems



Flat bands, superconductivity, topological states & Non-Fermi liquids

The pattern that captured my eyes:

Experiments: STM on nearly-commensurate charge-density wave in 1T-TaS₂



[Park, GYC, Lee, Yeom, Nat. Comm. (2019)]

[Sipos et. al. Nat. Mat. (2008)]

- **1.** Lateral size of domain wall network $\sim O(80)$ A.
- **2.** *Only* domain walls are metallic.

The pattern that captured my eyes:

Experiments: STM on nearly-commensurate charge-density wave in 1T-TaS₂



2. Only domain walls are metallic.

What's the electronic structure? Why superconducting?

The pattern that captured my eyes:

Experiments: STM on nearly-commensurate charge-density wave in 1T-TaS₂





Cf: certain density waves can be topological, too.

Can it be topological?

Any correlation-driven phenomena?

[Ref. JW Park, GYC, J Lee, HW Yeom, Nat. Comm. (2019)]

1. Lateral size of domain wall network $\sim O(80)$ A.

2. Only domain walls are metallic.



GYC, Soto-Garrido, Fradkin, Phys. Rev. Lett. (2015)

What's the electronic structure? Why superconducting?

To the 1st order approximation:



Problem: 1D mobility of electrons, combined with **2D** superstructures. [Lee, Geng, Park, Oshikawa, Lee, Yeom, **GYC***, Physical Review Letters (2020)]

This structure is *more common* than one naively thinks:



Twisted Bilayer Graphene [Yoo et.al. Nat. Matt. (2019)] Moiré MoSe₂ [Ma et.al. ACS Nano (2019)]

Patterned Network on Graphene [Forsythe et.al. Nano Lett (2018)]

More interesting examples?

Experiments: 1T-TiSe₂



1. Non-Fermi Transport $R \sim R_0 + A T^n$, varying exponent $n \approx 1 \sim 3$

2. Emerging superconductivity, and domain wall networks (Little-Park effect)

Correlation effect seems important in these materials!

Cam we explain these?

[1] Park, GYC, Lee, Yeom*, Nature Communications (2019)
[2] Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Physical Review Letters (2020)
[3] Lee, Oshikawa, GYC*, Physical Review Letters (2021)

To the 1st order approximation:



Problem: 1D mobility combined with **2D** superstructures.

[Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Physical Review Letters (2020)]



Wire length l_W vs. Thermal coherence $l_{k_BT} = \frac{\hbar v_F}{k_BT}$



- TiSe₂: O(10)K (assuming e.g. that the electrons are flowing along 1D domain walls)
- Twisted bilayer graphene: O(50)K (for 140 nm)
- TaS₂: O(100)K

Why this is important?

[Lee, Geng, ... GYC, PRL (2020)]

Lee, Oshikawa, GYC, PRL (2021)]

Low-T and high-T should be differently accessed in theory.

- TiSe₂: O(10)K (assuming e.g. that the electrons are flowing along 1D domain walls)

- Twisted bilayer graphene: O(50)K (for 140 nm)
- TaS₂: O(100)K

[Lee, Oshikawa, GYC*, Phys. Rev. Lett. 126, 186601 (2021)]

 $T_X \checkmark^{l_{k_BT}} = l_W$



- TiSe₂: O(10)K (assuming e.g. that the electrons are flowing along 1D domain walls)
- Twisted bilayer graphene: O(25)K (for 300 nm)
- TaS₂: O(100)K

2D limit: $T < T_X$

2D limit: Cascade of stable flat bands & Superconductivity



(with realistic parameters, geometry)

1. Not only one, but *many, many flat bands*.

2. Flatness is *stable*, i.e. protected by locality, time-reversal & crystal symmetry.

Stability = relevance to the real, experimental systems!

Of course, flat band is *not* new.

1. Kagome Lattice





- Single flat band
- NN-Hopping Only

Of course, flat band is *not* new.

1. Kagome Lattice



Of course, flat band is *not* new.

1. Kagome Lattice

What's new in our model is:

- 1. Multiple, *not just one*, Flat bands
- 2. Unusual Stability & Protecting symmetries

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Easier to observe the physics of flat bands without much tuning

- NN-Hopping

(sublattice symmetric hopping)

Emergence of flat bands & their stability

Numerics: flat band states have $\Psi(x) = 0$ at the nodes. [Cf. Bergman, Wu, Balents 2008]



Standing waves inside each wire.

Hence, flat bands are protected by:

(1) [Locality] Hopping is shorter than wire length [~ 80A in 1T-TaS₂]

- (2) [Symmetry] $D_6 \times T$ symmetry
- (3) Multiple standing waves = Repeated, Multiple flat bands

[Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Phys. Rev. Lett. 124, 137002 (2020)]



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2D limit: "Higher-order" topology

[Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Phys. Rev. Lett. 124, 137002 (2020)]





[Ref: Cho et al, Nat. Comm.(2017)]

2D limit: "Higher-order" topology

This looks very similar to the corner state of the higher-order T



PHYSICAL REVIEW LETTERS 123, 216803 (2019)

Higher-Order Topological Insulator in Twisted Bilayer Graphene

Moon Jip Park,^{1,*} Youngkuk Kim⁰,^{2,†} Gil Young Cho,^{3,‡} and SungBin Lee^{1,§}

...which one can actually make a more precise connection. Domain wall networks provide a natural platform for "higher-order" topology.

2D limit: "Higher-order" topology This looks very similar to the corner state of the higher-order T E Graphene in Lee^{1,§} Topological corner states Carbon atom HIGGEN HIGNER-Orde ...which one can actually make on. Domain wall networks provide a natural pology

Triptycene (Hatsugai's group, Phys. Rev. Mat. 2019)

2D limit: "Higher-order" topology

[Lee, Geng, Park, Oshikawa, Lee, Yeom, **GYC***, Phys. Rev. Lett. 124, 137002 (2020)]



LDOS peak ?

Hidden Higher-order Topology

[Ref: Yeom's group, Nat. Comm.(2017)]

Domain wall networks provide a natural platform for "higher-order" topology. (when gapped)

2D limit: Higher-order topology

[Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Phys. Rev. Lett. 124, 137002 (2020)]



Domain wall networks provide a natural platform for higher-order

HW Yeom (POSTECH)



- Cascades of stable flat bands
- Superconducting instabilities & experimental implications
- Higher-order topology & STM experiments

[Lee, Geng, Park, Oshikawa, Lee, Yeom, GYC*, Phys. Rev. Lett. (2020); Lee, Park, GYC, Yeom, submitted to Phys. Rev. Lett.]

1D limit: $T > T_X$



- TiSe₂: O(10)K (assuming e.g. that the electrons are flowing along 1D domain walls)
- Twisted bilayer graphene: O(25)K (for 300 nm)
- TaS₂: O(100)K

Quasi-1D: Plethora of Non-Fermi Liquids above T_x



Quasi-1D: Plethora of Non-Fermi Liquids above T_x



Toy Model: strange insulator phase

$$g(T) \approx g_0 + c T^{\alpha(k)}^{2K-2}$$

Toy model: repulsive, spinless electrons

Luttinger liquid: $H = \frac{v}{2} \int dx \left[\frac{1}{K} (\partial_x \theta)^2 + K (\partial_x \phi)^2 \right]$ (Luttinger parameter *K* > 1, repulsive) $\psi_3^\dagger \hspace{0.1 cm} \psi_2^\dagger \psi_3^{+}$ H.c. Q. What would happen if the temperature gets lowered? $oldsymbol{\psi}_3^\dagger oldsymbol{\psi}_1^{}+$ H.c. $m{\psi}_{f 1}^{ op}m{\psi}_{f 2}+{\sf H.c.}$ **A.** System evolves along the RG flow. Weak junction interactions

Toy model: repulsive, spinless electrons



What do we expect out of this fixed point?

(1) Electrically insulating for $T > T_X$.

- Even the electron hopping is irrelevant (!)

(2) Thermodynamically metal

- Luttinger liquid excitations are *intact*.

Electric conductivity in temperature T?

Decoupled fixed point emerges.

(Cf. it is also known as Neumann BC)

Relating "microscopic" junction to "macroscopic" network

$$\begin{pmatrix} I_1 \\ I_2 \\ I_3 \end{pmatrix} = \begin{pmatrix} G_S & (G_A - G_S)/2 & -(G_A + G_S)/2 \\ -(G_A + G_S)/2 & G_S & (G_A - G_S)/2 \\ (G_A - G_S)/2 & -(G_A + G_S)/2 & G_S \end{pmatrix} \begin{pmatrix} V_1 \\ V_2 \\ V_3 \end{pmatrix}$$

Key observations:

(1) G_s and G_A are determined by the fixed point of the 0D junction

(2) G_s and G_A determine the 2D conductivity:

$$g_{xx}(T) = \sqrt{3} \frac{G_s(T)}{4} \& g_{xy}(T) = \frac{G_A(T)}{4}$$

 $(g_{ab} = \text{``macroscopic'' data}, G_{S/A} = \text{``microscopic'' data})$



Conductance of the junction

Toy model: repulsive, spinless electrons



Decoupled fixed point emerges.

(**Cf.** it is also known as Neumann BC)

Perturbative expansions to the leading order are...

$$g_{xx}(\mathbf{T}) \approx \mathbf{0} + \frac{\sqrt{3}\pi e^2 t^2}{2h} \tau_c^{2K} \frac{\pi^{2K-1} \Gamma\left(\frac{1}{2}\right) \Gamma(K)}{\Gamma\left(\frac{1}{2}-K\right)} \mathbf{T}^{2K-2}$$
(for $K > 1$)
$$g_{xy}(\mathbf{T}) \approx \mathbf{0} + \mathbf{O}\left(\mathbf{T}^{2K-2}\right)$$

Determined by the *leading irrelevant operator* at the fixed point

(universal data of the fixed point)

For this "decoupled" fixed point, $\Delta = K \implies \delta g \sim T^{2\Delta-2}$

Locally critical umklapp scattering and holography (AdS/CFT duality)

Sean A. Hartnoll[▶] and Diego M. Hofman[♯]

Abstract

Efficient momentum relaxation through umklapp scattering, leading to a power law in temperature d.c. resistivity, requires a significant low energy spectral weight at finite momentum. One way to achieve this is via a Fermi surface structure, leading to the well-known relaxation rate $\Gamma \sim T^2$. We observe that local criticality, in which energies scale but momenta do not, provides a distinct route to efficient umklapp scattering. We show that umklapp scattering by an ionic lattice in a locally critical theory leads to $\Gamma \sim T^{2\Delta_{k_L}}$. Here $\Delta_{k_L} \geq 0$ is the dimension of the (irrelevant or marginal) charge density operator $J^t(\omega, k_L)$ in the locally critical theory, at the lattice momentum k_L . We illustrate this result with an explicit computation in locally critical theories described holographically via Einstein-Maxwell theory in Anti-de Sitter spacetime. We furthermore show that scattering by random impurities in these locally critical theories gives a universal $\Gamma \sim (\log \frac{1}{T})^{-1}$.

$$R(T)\sim\frac{1}{T^{2\Delta}}$$

We have achieved a microscopic model

of strange insulator behaviors!

Experiment in graphene ?

ARTICLE

https://doi.org/10.1038/s41467-019-11971-7

OPEN

Giant oscillations in a triangular network of onedimensional states in marginally twisted graphene

S.G. Xu (b^{1,2,5}, A.I. Berdyugin (b^{1,5}, P. Kumaravadivel (b^{1,2}, F. Guinea¹, R. Krishna Kumar^{1,2}, D.A. Bandurin¹, S.V. Morozov³, W. Kuang¹, B. Tsim (b^{1,2}, S. Liu⁴, J.H. Edgar⁴, I.V. Grigorieva (b¹, V.I. Fal'ko (b^{1,2}, M. Kim (b¹) & A.K. Geim (b^{1,2})



Hopefully to see this in the future experiments

Remark:

Power-law correction in temperature T In all cases, we find: (fixed by the leading irrelevant operator) $g(T) \approx \mathbf{g_0} + c T^{\alpha(K)}$ Universal conductance of the junction "K" is the exactly marginal parameter. (determined by the junction BCs) This will *continuously evolve* when experimental parameters,

e.g., gating or pressure, are changed.

This is markedly different from a regular 2D Fermi liquid! [Lee, Oshikawa, **GYC***, Phys. Rev. Lett. 126, 186601 (2021)]

Strongly Reminiscent of Experiments...



1. Non-Fermi Transport $R \sim R_0 + A T^n$, varying exponent $n \approx 1 \sim 3$

2. Emerging superconductivity, and domain wall networks (Little-Park effect)

Correlation effect seems important in these materials!

Conclusions



- Cascades of stable flat bands
- Superconducting instabilities & experimental implications
- Higher-order topology & STM experiments
- Non-Fermi liquids (high-T regime)

If there's 1 min...

Steady non-equilibrium quantum states:

Article

Steady Floquet–Andreev states in graphene Josephson junctions

 $\sim\! \textit{O}(10^{17})$ longer life time than previous pulse-generated Floquet states



Upshot: graphene + continuous irradiation of microwaves = steady Floquet states

$$\beta = ev_F |\vec{E}|/\hbar\omega$$

Diagnostics of steady states: spectral sum rules

[Park, Lee, (...), **GYC,** Lee, Nature (2022)]

